2SC5808



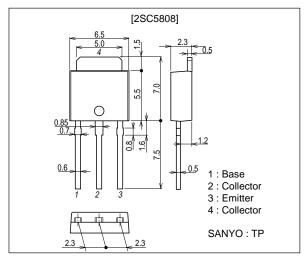
# **Switching Power Supply Applications**

#### **Features**

- · High breakdown voltage.
- · High speed switching.
- · Wide ASO.
- · Adoption of MBIT process.

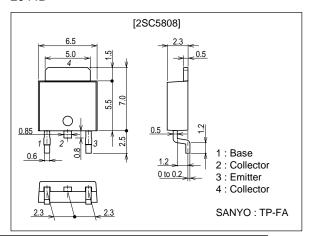
### **Package Dimensions**

unit : mm 2045B



### **Package Dimensions**

unit : mm 2044B



- Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.
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# **Specifications**

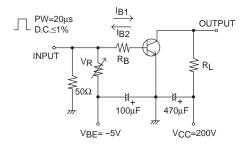
## Absolute Maximum Ratings at Ta= $25^{\circ}C$

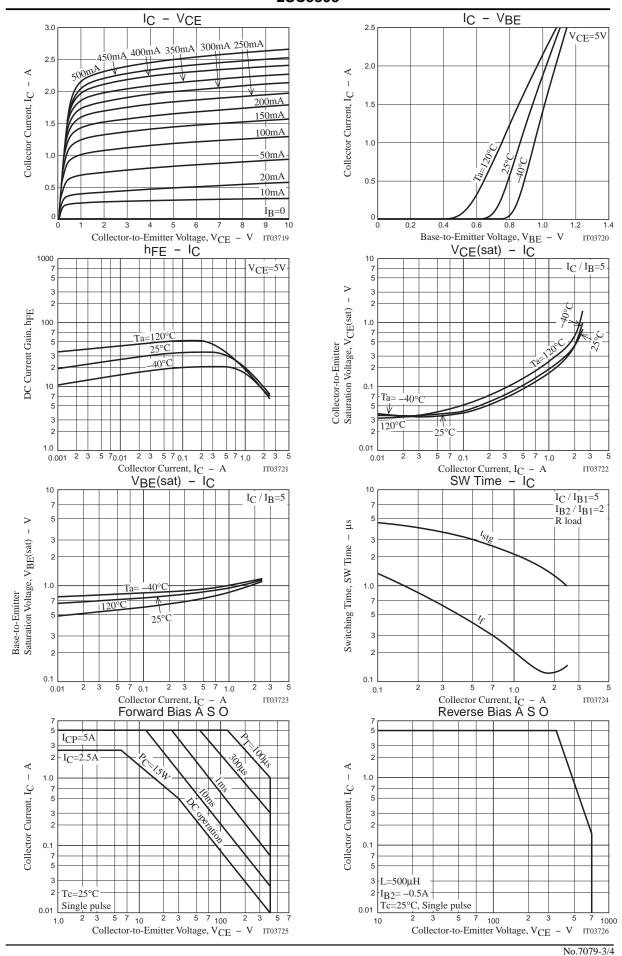
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		700	V
Collector-to-Emitter Voltage	VCES		700	V
Collector-to-Emitter Voltage	VCEO		400	V
Emitter-to-Base Voltage	VEBO		8	V
Collector Current	IC		2.5	Α
Collector Current (Pulse)	ICP	PW≤300μs, duty cycle≤10%	5	Α
Base Current	lΒ		1.2	Α
Collector Dissipation	Do		1	W
	PC	Tc=25°C	15	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### Electrical Characteristics at Ta=25°C

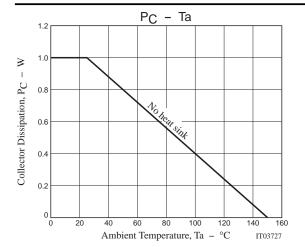
Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Collector Cutoff Current	ICBO	V <sub>CB</sub> =400V, I <sub>E</sub> =0			10	μΑ
Emitter Cutoff Current	IEBO	VEB=5V, IC=0			10	μΑ
DC Current Gain	hFE1	V <sub>CE</sub> =5V, I <sub>C</sub> =0.3A	20		50	
	hFE2	VCE=5V, IC=1.2A	10			
	hFE3	VCE=5V, IC=1mA	10			
Gain-Bandwidth Product	fŢ	V <sub>CE</sub> =10V, I <sub>C</sub> =0.3A		20		MHz
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz		20		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> =1.2A, I <sub>B</sub> =0.24A			0.8	V
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	IC=1.2A, IB=0.24A			1.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =1mA, I <sub>E</sub> =0	700			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=5mA, RBE=∞	400			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=1mA, IC=0	8			V
Turn-On Time	ton	V <sub>CC</sub> =200V, I <sub>C</sub> =1.5A, I <sub>B1</sub> =0.3A,			0.5	μs
		I <sub>B2</sub> =-0.6A, R <sub>L</sub> =133Ω				
Storage Time	t <sub>stg</sub>	V <sub>CC</sub> =200V, I <sub>C</sub> =1.5A, I <sub>B1</sub> =0.3A,			2.5	μs
		I <sub>B2</sub> =-0.6A, R <sub>L</sub> =133Ω				
Fall Time	tf	VCC=200V, IC=1.5A, IB1=0.3A,			0.25	μs
		I <sub>B2</sub> =-0.6A, R <sub>L</sub> =133Ω				

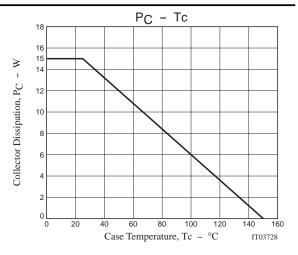
## **Switching Time Test Circuit**





#### 2SC5808





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